# **CEPC Silicon Drift Chamber Tracker**



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#### Outline

- Introduction to SDT
- SDT v1.0: Baseline configure with two Drift Chambers
- SDT v1.1: Small Tracker Options
- SDT v2 Plan



Final two detectors likely to be a mix and match of different options

Joao da Costa

## Motivation for Silicon + Drift Chamber Tracker

- Explore a different tracker option for CEPC
- Capable for both tracking and particle ID (flavor, JES, jet flavor,...)
- Combine the Silicon technology (strip, CMOS) and Drift chamber technology (IDEA, dE/dx, cluster counting, ...)
- Provide concrete platform to integrate smaller crystal ECAL
- Open path for better particle ID with future timing layer (LGAD) between SDT and crystal ECAL

#### CEPC Silicon + Drift Chamber Tracker: v1.0

- Based on the baseline Silicon + TPC
- Replace TPC layers with two drift chamber layers
  - SIT 3&4 set at R=1.0m / larger cell size of DC than TPC



#### SDT v1: Geometry of the detector layers

- Fast Simulation Tool : LiC Detector Toy 2.0 (LDT) developed for design studies and optimizing the detector configuration
- Reflecting the geometry (tracking part) of the baseline concept



A layout of the tracking system set in the simulation

#### Impact parameter and momentum resolution



• No change for impact para. reso. and slight degradation for barrel momentum reso.

## Number of hit layers (per track)

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40	40 Time Projection Chamber (TP	C)			
41	41 sigma^2=sigmaO^2+sigma1^2*s	in(b	eta)^2+Cdiff^2	2*6mm/h*sin(theta)*Ldrift[m]	
42	42 Number of layers	:	222		
43	43 Radii [mm]	:	384,1716		
44	44 Upper limit in z [mm]	:	2225		
45	45 Lower limit in z [mm]	:	-2225		
46	46 Efficiency RPhi	:	1	TPC $\cdot$ 222 lay	/ers
47	47 Efficiency z	:	1		
48	48 Thickness [rad. lengths]	:	0.00005194		
49	49 sigmaO(RPhi) [1e-6m]	:	50		
50	50 sigma1(RPhi) [1e-6m]	:	900		
51	51 Cdiff(RPhi) [1e-6m/sqrt(m)	]:	25		
52	52 sigmaO(z) [1e-6m]	:	400		
53	53 sigma1(z) [1e-6m]	:	0		
54	54 Cdiff(z) [1e-6m/sqrt(m)	]:	80		

• ~ 90 decrease for barrel with SDT v1.0





#### Silicon + Drift Chamber Tracker: v1.1

• Smaller radius : R = 1.5 m (reduced size for crystal ECAL)



#### Performance comparison v1.1 vs. baseline



#### Performance comparison v1.0 and v1.1 vs. baseline



#### Recoil mass resolution v1.0 and v1.1

• ~12% increase



#### SDT v2.0

- Switch to CEPCSW: <u>https://github.com/cepc/CEPCSW</u>
  - Implement SDT basic config
  - Extract Hit Info from Drift Chamber

#### CEPCSW is based on Key4hep

- Common tools
  - CMake: building & deployment
    - Gaudi cmake macros
  - Spack: Package manager
    - K4spack: <u>https://github.com/key4hep/k4</u> <u>-spack</u>
  - Git: version control
    - https://github.com/cepc/CEPCSW
  - CVMFS: software distribution
    - CEPC specific: /cvmfs/cepcsw.ihep.ac.cn/ prototype
- Layered External Libraries
  - CEPC specific libraries
  - Key4hep libraries
  - LCG libraries (from CERN CVMFS)



Tao Lin

### Summary and Plan

- Silicon + Drift Chamber as an alternative detector concept design for CEPC for both high momentum resolution and particle ID
- SDT v1.0 with 2 Drift chambers has no change for the impact paramter resolution, but slight degradation for momentum resolution compared with baseline
  - Dereased 90 numbers of hit layers in barrel region.
- SDT v1.1 (R=1.5m) : no change for impact paramter resolution, increased momentum resolution for certain momentum (<~2)
  - ~ 12% increase for the dimuon recoil resolution
- SDT v2: Migration to new software framework: CEPCSW
  - dE/dx, material budget, S/D layers, ....